NSN 5961-01-179-3469

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View Online at https://aerobasegroup.com/nsn/5961-01-179-3469

View Offiline at https://derobasegroup.com/histi/5501-01-175-5405
Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
1.750 inches
Overall Diameter:
0.335 inches
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Internal Junction Configuration:
N pn
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
75.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
800.00 milliamperes source cutoff current
Power Rating Per Characteristic:
3.0 watts small-signal input power, common-collector preset
Transfer Ratio:
300.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
81349-mil-s-19500/251 government specification
Shelf Life:

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N/a

Unit Of Measure:

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No

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